

ES3DHE3_A/I



Vishay / Semiconductor - Diodes Division

DIODE UFAST 200V 3A DO214AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

 [ES3DHE3_A/I.pdf](#)

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Out Stock

0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

Images are for reference only.

See Product Specifications for product details.

If you are interested to buy ES3DHE3_A/I, Just Email us.

Sales@zeanoit.com

our sales team will reply you within 24 hours

Shopping Process

1

Confirm the product

2

submit the order

3

payment

4

wait for delivery

5

receive the goods

Specifications

Voltage - Forward (Vf) (Max) @ If:	900mV @ 3A
Voltage - DC Reverse (Vr) (Max):	200V
Supplier Device Package:	DO-214AB, (SMC)
Speed:	Fast Recovery = 200mA (Io)
Series:	Automotive, AEC-Q101
Reverse Recovery Time (trr):	30ns
Packaging:	Tape & Reel (TR)
Package / Case:	DO-214AB, SMC
Operating Temperature - Junction:	-55°C ~ 150°C
Mounting Type:	Surface Mount
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	10µA @ 200V
Current - Average Rectified (Io):	3A
Capacitance @ Vr, F:	45pF @ 4V, 1MHz

Related products



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ES3F
VISHAY

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ES3F-E3/57T
DIODE GEN PURP 300V 3A DO214AB
Vishay Semiconductor Diodes Division

RFQ



ES3DHE3/57T
DIODE GEN PURP 200V 3A DO214AB
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DIODE GEN PURP 300V 3A DO214AB
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ES3DHE3/9AT
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